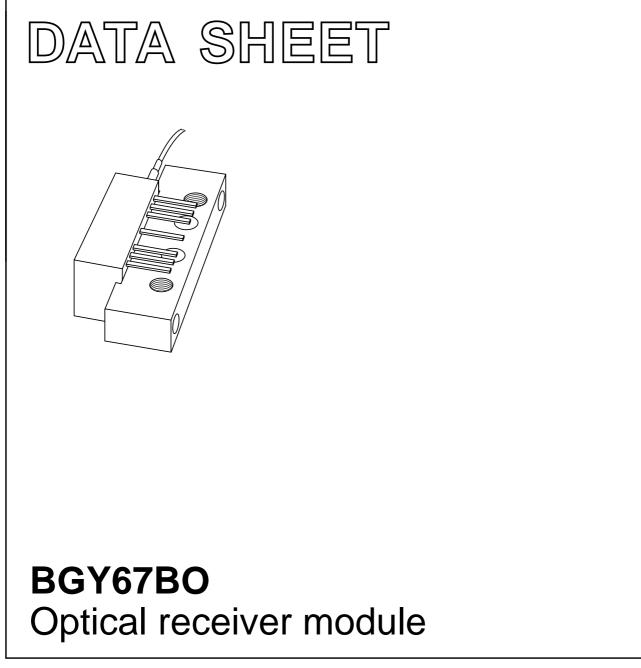
## DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1998 Mar 13 2001 Sep 27



### BGY67BO

### FEATURES

- Excellent linearity
- Extremely low noise
- Excellent flatness
- Standard CATV outline
- Rugged construction
- Gold metallization ensures excellent reliability.

### APPLICATIONS

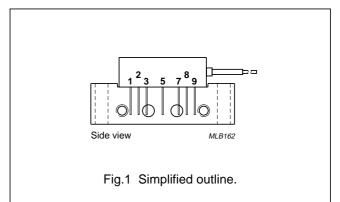
• Reverse receiver amplifier in two-way CATV systems in the 5 to 300 MHz frequency range.

#### DESCRIPTION

Hybrid high dynamic range optical amplifier module in a SOT115U package operating at a voltage supply of 24 V (DC). The module contains a monomode optical input suitable for wavelengths from 1290 to 1600 nm, a terminal to monitor, the pin diode current and an electrical output with an impedance of 75  $\Omega$ .

### PINNING - SOT115U

PIN	DESCRIPTION	
1	monitor current	
2	common	
3	common	
5	+V <sub>B</sub>	
7	common	
8	common	
9	output	



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		5	300	MHz
S <sub>22</sub>	output return losses	f = 5 to 300 MHz	15	-	dB
	optical input return losses		40	-	dB
d <sub>2</sub>	second order distortion		-	-70	dBc
F	equivalent noise input	f = 10 to 300 MHz	-	7	pA/√Hz
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	160	190	mA

#### HANDLING

Fibreglass optical coupling: maximum tensile strength = 5 N; minimum bending radius = 35 mm.

### CAUTION

This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling. For further information, refer to Philips specs.: SNW-EQ-608, SNW-FQ-302A and SNW-FQ-302B.

### BGY67BO

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		5	300	MHz
T <sub>stg</sub>	storage temperature		-40	+85	°C
T <sub>mb</sub>	operating mounting base temperature		-20	+85	°C
P <sub>in</sub>	optical input power	continuous	-	5	mW
ESD	ESD sensitivity	human body model; R = 1.5 k $\Omega$ ; C = 100 pF	500	_	V

### CHARACTERISTICS

**Table 1** Bandwidth 5 to 300 MHz;  $V_B = 24 V$ ;  $T_{mb} = 30 \degree C$ ;  $Z_L = 75 \Omega$ .

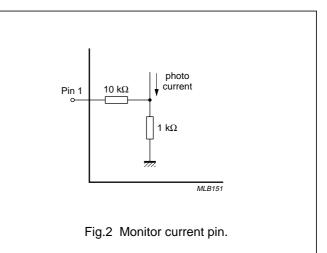
SYMBOL	PARAMETER CONDITIONS		MIN.	MAX.	UNIT
S	responsivity	λ = 1300 nm	800	-	V/W
FL	flatness of frequency response		-	±0.3	dB
S <sub>22</sub>	output return losses f = 5 to 300 MHz 15		-	dB	
	optical input return losses		40	-	dB
d <sub>2</sub>	second order distortion	note 1	-	-70	dB
d <sub>3</sub>	third order distortion	note 2	_	-80	dB
F	equivalent noise input	f = 10 to 300 MHz	_	7	pA/√Hz
s <sub>λ</sub>	spectral sensitivity	$\lambda = 1310 \pm 20 \text{ nm}$	0.85	-	A/W
		$\lambda = 1550 \pm 20 \text{ nm}$	0.9	-	A/W
λ	optical wavelength		1290	1600	nm
L	length of optical fibre	fibre; SM type; 9/125 μm	1	-	m
I <sub>tot</sub>	total current consumption (DC)	note 3	160	190	mA

#### Notes

- 1. Two laser test; each laser with 40% modulation index;  $f_p = 20.25 \text{ MHz}; P_p = 0.5 \text{ mW};$   $f_q = 34 \text{ MHz}; P_q = 0.5 \text{ mW};$ measured at  $f_p + f_q = 54.25 \text{ MHz}.$
- Three laser test; each laser with 40% modulation index;
  f = 125.25 MHz; P = 0.33 mW;

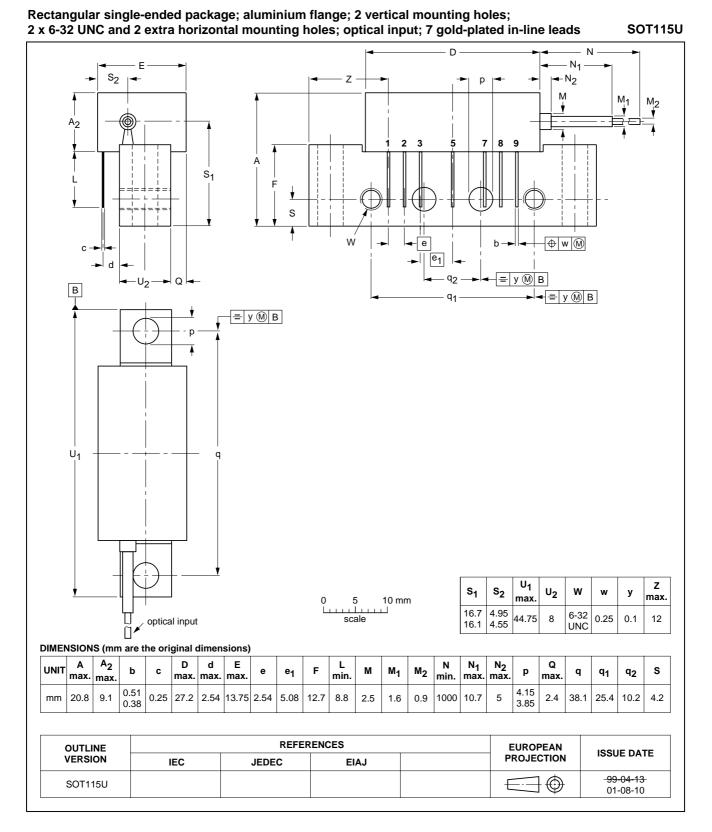
 $\begin{array}{l} f_p = 125.25 \text{ MHz}; \ P_p = 0.33 \text{ mW}; \\ f_q = 110.25 \text{ MHz}; \ P_q = 0.33 \text{ mW}; \\ f_r = 135.25 \text{ MHz}; \ P_r = 0.33 \text{ mW}; \\ \text{measured at } f_p + f_q - f_r = 100.25 \text{ MHz}. \end{array}$ 

3. The module normally operates at  $V_B = 24$  V, but is able to withstand supply transients up to 30 V.



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### PACKAGE OUTLINE



BGY67BO

### DATA SHEET STATUS

DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

### Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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